CXA1445M

HDD Equalizer (Pulse Slimming) IC

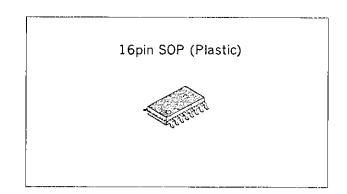
Description

The CXA1445M is an IC for HDD read data equalizers (cosine equalization).

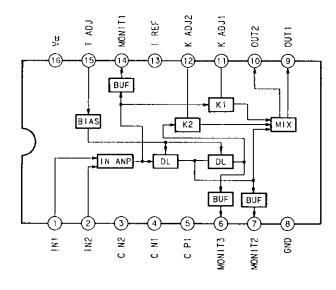
The delay circuit realized through the adoption of an active filter circuit dispenses from the expensive delay line so far in use. Delay time may be changed at will by altering the resistance value.

Features

- The delay circuit obtained through an active filter circuit dispenses from external delay lines. Delay time adjustment is possible by changing the external resistance value.
- Mix ratio adjustment of K1 and K2 is possible by changing the external resistance value.
- 5V single power supply



Block Diagram and Pin Configuration



Absolute Maximum Ratings (Ta=25°C)

Supply voltage

 V_{cc}

7

• Storage temperature

 $\mathsf{T}_{\mathsf{stg}}$

-55 to +150

.C

Operating Conditions

Supply voltageOperating temperature

 V_{CC}

4.5 to 5.5 -20 to +75

.C A

Pin Description

No.	Symbol	Voltage	Equivalent circuit	Description				
1	iN1	2.0V	0V 147 16κ 777 16κ 16κ 2οομ 2οομ 2οομ 2οομ 2οομ 2οομ 2οομ 2ο	Inputs data signals from read amplifier as differential signals through a capacitor.				
2	IN2			Internal impedance is approx. $16k\Omega$.				
3	CN2	1.7V	3(4) 147 W	Connects capacitor (0.01 µF) between this				
4	CN1		GND ##	pin and GND to control noise in the circuit.				
5	CP1	3.5V	να 147 5	Connects capacitor (0.01 $\mu\text{F})$ between this pin and V_{CC} to control noise in the circuit.				
6	MONIT3	2.4V	Vα 147 6	Monitor pin output through buffer after input signal passing two delay lines.				
7	MONIT2	2.4V	Vec 147 (7) - WV GND 7/7 200 μ GND 7/7	Monitor pin output through buffer after input signal passing the first delay line.				

No.	Symbol	Voltage	Equivalent circuit Description		
. 8	GND	07	GND pin for all circuits		
9	OUT1	3.8V	9 10 ¥ 4K GND 7/// GND 7///	Signal output pin. Equalized signal is output to pulse detector.	
11	K ADJ1	1.2V	147 111 GND 777	A resistor is connected to set K_1 . $K_1=a_{\Gamma}$ -prox. 0.25 at $12k\Omega$ (Typ.) Varying the resistance value from ∞ to $4k\Omega$ varies K_1 from 0 to 0.3.	
12	K ADJ2	1.2V	A resistor is connected to set K_2 . prox. 0.25 at $12k\Omega$ (Typ.) Vary resistance value from ∞ to $4k\Omega$ value from 0 to 0.3.		
13	I REF	1.2V	147 13 W	$12 k\Omega$ resistor is connected to obtain internal reference current	
14	MONIT1	2.4V	Output monitor pin of IN AMP		
15	T ADJ	4.0	147 (15) WV TO SOLUTION OF THE	A resistor is connected to set delay time. Set to 58ns at $10k\Omega$ (Typ.). Varying from 5 to $25k\Omega$ produces a change from 40 to 150ns.	
16	V _{cc}	5٧		Connects 5V power supply.	

Electrical Characteristics

S3 and S4 taken as "a" side unless specified especially.

 $(Ta = 25^{\circ}C, V_{CC} = 5V)$

Item	Symbol	Conditions	Test point	Min.	Тур.	Max.	Unit
Current consumption	l_{cc}	S1=0N, S2=0N	IM1	8	11	14	mA
Mix ratio accuracy &	K ₁	$f=200$ kHz $V_{IN}=100$ m V_{P-P} $S1=ON$, $S2=OFF$	VM1	-10	0	+10	%
Mix ratio accuracy *	K ₂	$f=200kHz V_{1N}=100mVp-p$ S1=OFF, S2=ON	VM1	-10	0	+10	%
Delevitime a sourcevite	$T_\mathtt{L}$	$f=6MHz$ $V_{1N}=100mVp-p$	VM1	-13	0	+13	%
Delay time accuracy *	T _H	f=10MHz V _{IN} =100mVp-p	VM1	-22	0	+22	%
Frequency FC characteristics		-3 dB $V_{IN} = 25$ m V_{P-P} S1 = OFF, S2 = OFF	VM1	15			MHz
Gain	GAIN	f=200kHz S1=0FF, S2=0FF	VM1	7.5	9	10.5	dB
Maximum input V _{INMAX}		f=3MHz THD≦5% S1=OFF, S2=OFF	VM1	300			mVp∙p
Output noise voltage	V_{NOISE}	S1=OFF, S2=OFF S3=b, S4=b	VM2			630	μV_{rms}

^{*}With the center value of mix ratio and delay time taken as $K_{1,2}=0.255$ and T=58ns.

The testing methods of mix ratio and delay time can be defined as follows: Equalizer frequency characteristics taken as H (W). To find K_1 , suppose $K_2 = 0$ (S2=OFF), then,

$$|H(W)|^2 = 1 + K_1^2 - 2K_1 \cos \omega \tau$$

Here $K_1 = 0$ (S1 = OFF), 200kHz gain is taken as G_0 (dB). When a certain K_1 is set, 200kHz gain is taken as G_1 (dB). K_1 is calculated through the following formula:

$$K_1 = 1 - 10^{\frac{G_1 - G_0}{20}}$$

 K_2 is solved in a similar way by supposing $K_1=0$ (S1=OFF)

Delay time $T_{\scriptscriptstyle L}$ is calculated through the following formula:

S1 and S2 are OFF (where K_1 and K_2 are set to 0), 200kHz and 6MHz gain are taken as G_0 , G_2 (dB). When a certain K_1 and K_2 (S1 and S2=ON, K_1 = K_2) are set, 200kHz and 6MHz gain are taken as G_1 ', G_3 ' (dB). T_L is calculated through the following fournula:

$$T_{L} = \frac{1}{\omega} \cos^{-1} \left[\frac{1 - 10^{\frac{G_{1} - G_{2}}{20}}}{2K} \right]$$

K is caluculated through the following formula:

$$K = \frac{1 - 10^{\frac{G_1' - G_0}{20}}}{2}$$

As the equalizer frequency characteristics have exceeded the gain peak at f=10MHz, delay time T_H when 10MHz gain are taken as G_3 , G_2 (dB) is expressed by the following formula:

$$T_{H} = \frac{1}{\omega} \left\{ 2\pi - \cos^{-1} \left[\frac{1 - 10^{\frac{G_{3}' - G_{1}}{20}}}{2K} \right] \right\}$$

The calculating method for this delay time is applied when it is set around 60ns. For setting to any other delay time, the frequency used to test the gain should be changed.

Calculation of delay time

T ADJ1 pin current is taken as I, while delay time is obtained approximately through the following formula:

$$\Delta t = \frac{5.4 \times 10^{-12}}{I}$$

As T ADJ pin voltage is 4.0V, the resistance to be connected to T ADJ pin is taken as R. We have

$$I = \frac{1.0}{R}$$

T ADJ pin voltage changes slightly according to the connected resistance value. However, ignoring this fluctuation, the relation between the delay time and R is given through the following formula:

$$\Delta t = \frac{5.4 \times 10^{-12}}{1.0} \times R$$
$$= 5.4 \times 10^{-12} \times R$$

When $R=10k\Omega$, we have

$$\Delta t = 5.4 \times 10^{-12} \times 10 \times 10^{3} = 54 \text{ ns}$$

Calculation of mix ratio K1, K2

Mix ratio calculation K_1 generally follows the following formula:

$$2K_1 = \frac{I1}{I1 + I2}$$
 II: 11 pin (K ADJ1) current
I2: 13 pin (I REF) current

K ADJ1 pin, I REF pin voltage is approx. 1.2V As a $12k\Omega$ is connected to I REF pin. I2= 100μ A. K ADJ1 pin voltage changes slightly according to the connected resistance value. However, ignoring this fluctuation, the relation between the mix ratio and R is given through the following formula:

$$I1 = \frac{1.2}{R}$$

Therefore, the relation between K₁ and R is as follows:

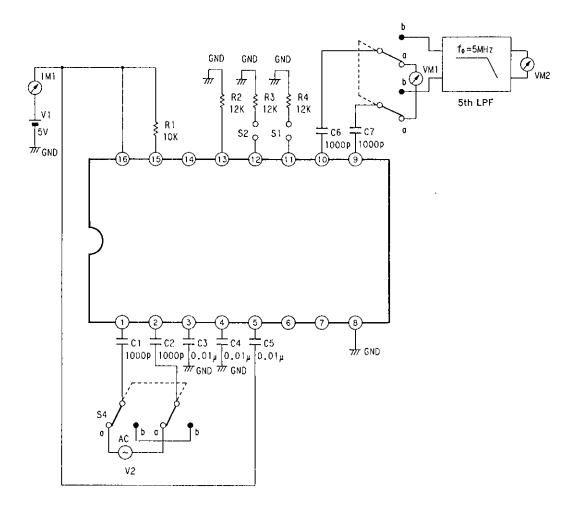
$$K_1 = \frac{0.6}{1.2 + 100 \times 10^{-6} \times R}$$

For example, when $R = 12k\Omega$, we have

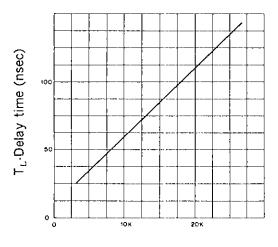
$$K_1 = \frac{0.6}{1.2 + 100 \times 10^{-6} \times 12 \times 10^3} = 0.25$$

K₂ is solved in a similar way as being 12 pin K ADJ2 current.

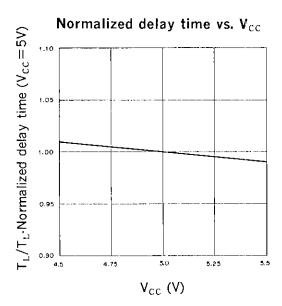
Electrical Characteristics Test Circuit



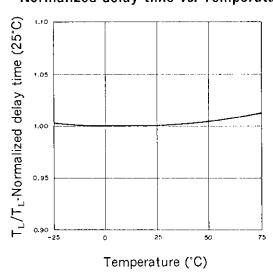
Delay time vs. Setting resistance



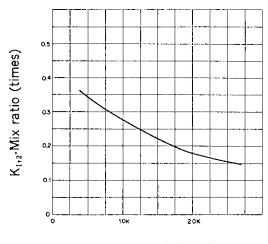
R (T ADJ) (Ω)



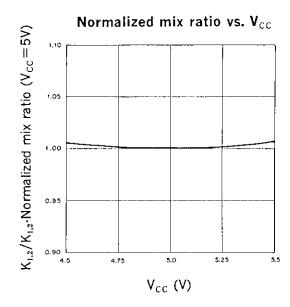
Normalized delay time vs. Temperature



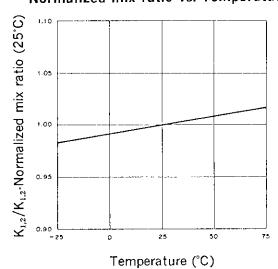
Mix ratio vs. Setting resistance



R (K ADJ1,2) (Ω)

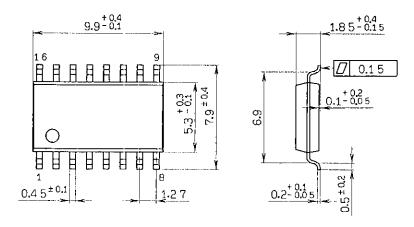


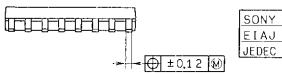
Normalized mix ratio vs. Temperature



Package Outline Unit: mm

16pin SOP (Plastic) 300mil 0.2g





SONY	NAME	SOP-16P-L01
EIAJ	NAME	*SOP016-P-0300-A
JEDEC	CODE	